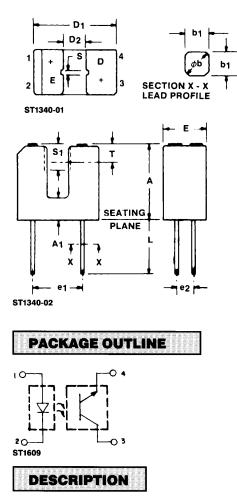


H22A4/5/6

PACKAGE DIMENSIONS



The H22A Slotted Optical Switch is a gallium arsenide light emitting diode coupled to a silicon photodarlington in a plastic housing. The packaging system is designed to optimize the mechanical resolution, coupling efficiency, ambient light rejection, cost and reliability. The gap in the housing provides a means of interrupting the signal with an opaque material, switching the output from an "ON" to an "OFF" state.

-					
SYMBOL	MILLIM	ETERS	INC	NOTES	
0	MIN.	MAX.	MIN.	MAX.	10120
Α	10.7	11.0	.422	.433	
Α,	3.0	3.2	.119	.125	
®b	.600	.750	.024	.030	2
b 1	.50 NOM.		.020	NOM.	2
D,	11.6	12.0	.457	.472	
D ₂	3.0	3.3	.119	.129	
e 1	6.9	7.5	.272	.295	
e ₂	2.3	2.8	.091	.110	
E	6.15	6.35	.243	.249	
L	8.00		.315		
S	.85	1.0	.034	.039	
S ₁	3.45	3.75	.136	.147	
Т	2.6 N	IOM.	.103	NOM.	3

NOTES:

- 1. INCH DIMENSIONS ARE DERIVED FROM MILLIMETERS.
- FOUR LEADS. LEAD CROSS SECTION IS CONTROLLED BETWEEN 1.27mm (.050") FROM SEATING PLANE AND THE END OF THE LEADS.
- 3. THE SENSING AREA IS DEFINED BY THE "S" DIMENSION AND BY DIMENSION "T" ±0.75mm (±.030 INCH).

A 45 19 19			 	
	-		 10 V	1.00
F		 1.0		
100 W W 100 B 1				

- Opaque housing
- Low cost
- .035" apertures
- High I_{C(ON)}



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C	Unless Otherwise Specified)
Storage Temperature	
Operating Temperature	55°C to +100°
Soldering:	
Lead Temperature (Iron)	240°C for 5 sec. ^{(3,4}
Lead Temperature (Flow)	
NPUT DIODE	
Continuous Forward Current	
Reverse Voltage	
Power Dissipation	100 mW
OUTPUT TRANSISTOR	
Collector-Emitter Voltage	
Emitter-Collector Voltage	
Power Dissipation	

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
INPUT DIODE						
Forward Voltage	VF	_		1.7	V	$I_F = 60 \text{ mA}$
Reverse Breakdown Voltage	V _R	6.0		_	V	$I_{R} = 10 \mu A$
Reverse Leakage Current	I _R			1.0	μA	$V_R = 3 V$
OUTPUT TRANSISTOR						
Emitter-Collector Breakdown	BV_{ECO}	6			V	$I_{E} = 100 \ \mu A, Ee = 0$
Collector-Emitter Breakdown	BV _{CEO}	55			V	$I_c = 1 \text{ mA}, \text{Ee} = 0$
Collector-Emitter Leakage	I _{CEO}	_		100	nA	$V_{\text{ce}} = 45 \text{ V}, \text{ Ee} = 0$
COUPLED						
On-State Collector Current	I _{C(ON)}		See page 3.		mA	
Saturation Voltage	$V_{CE(SAT)}$		See page 3.		V	
Turn-On Time	t _{on}		See page 3.		μS	
Turn-Off Time	t _{off}		See page 3.		μS	

NOTES

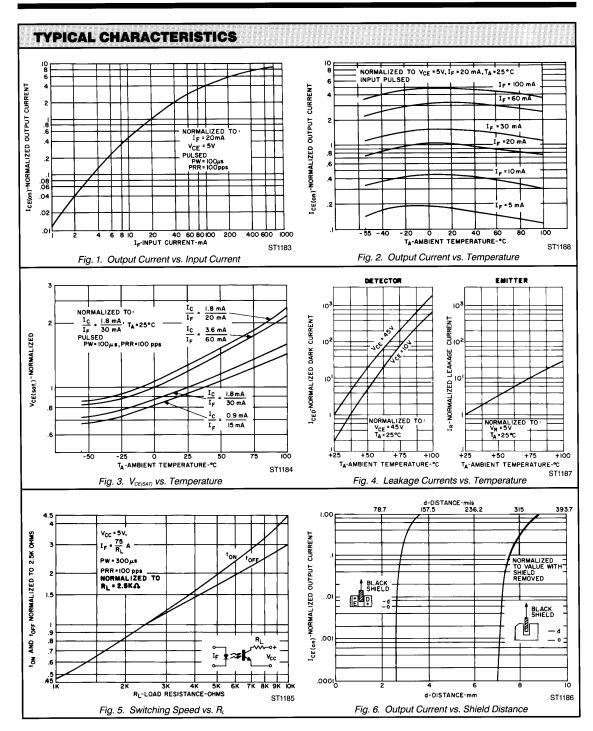
- Derate power dissipation linearly 1.33 mW/°C above 25°C.
 Derate power dissipation linearly 2.00 mW/°C above 25°C.
 RMA flux is recommended.

- Methanol or Isopropyl alcohols are recommended as cleaning agents.
 Soldering iron tip ¼e" (1.6 mm) from housing.



IC(ON) VCE(SAT) tons A	ND t _{off}					
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
ON-STATE COLLECTOR	RCURRENT					
H22A4	I _{C(ON)}	0.15	-	_	mA	$I_F = 5mA$, $V_{CE} = 5V$
H22A5	I _{C(ON)}	0.30	_	_	mA	$I_F = 5mA$, $V_{CE} = 5V$
H22A6	I _{C(ON)}	0.60			mA	$I_{\rm F}=5{\rm mA},V_{\rm CE}=5{\rm V}$
H22A4		1.0			mA	$I_{\rm F} = 20 {\rm mA}, V_{\rm CF} = 5 {\rm V}$
H22A5	I _{C(ON)}	2.0		_	mA	$I_{\rm F} = 20 {\rm mA}, V_{\rm CE} = 5 {\rm V}$
H22A6	I _{C(ON)}	4.0	_		mA	$I_{\scriptscriptstyle F}=20mA,V_{\scriptscriptstyle CE}=5V$
H22A4	I _{C(ON)}	1.9			mA	$I_{\rm F} = 30 {\rm mA}, V_{\rm CE} = 5 {\rm V}$
H22A5		3.0	_	_	mA	$I_{\rm F} = 30 {\rm mA}, V_{\rm CE} = 5 {\rm V}$
H22A6	I _{C(ON)}	5.5			mA	$I_{\rm F}=30{\rm mA},V_{\rm CE}=5{\rm V}$
SATURATION VOLTAGE						*
H22A5	V _{CE(SAT)}		—	0.40	V	$I_{\rm F} = 20 {\rm mA}, I_{\rm c} = 1.8 {\rm mA}$
H22A6	$V_{\text{CE(SAT)}}$			0.40	V	$I_{\scriptscriptstyle F}=20mA,I_{\scriptscriptstyle C}=1.8mA$
H22A4				0.40	V	$I_{\rm F} = 30 {\rm mA}, I_{\rm c} = 1.8 {\rm mA}$
Turn-On Time	t _{on}	_	8		μS	$V_{cc} = 5V, I_F = 30 \text{ mA}, R_L = 2.5Ks$
Turn-Off Time	t _{off}	_	50		μS	$V_{cc} = 5V, I_F = 30 \text{ mA}, R_L = 2.5KS$





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